LOW EMI CLOCK GENERATOR

Description

The MK1704A is an upgraded version of the MK1704 and is recommended for all new designs. It offers more reduction in the frequency amplitude peaks and will support frequencies up to 140 MHz.

The MK1704A generates a low EMI output clock from a clock input. The part is designed to dither the LCD interface clock or other clocks for flat panel graphics controllers. The MK1704A uses IDT's proprietary mixture of analog and digital Phase Locked Loop (PLL) technology to synthesize the frequency. It also uses IDT's patented technique to spread the frequency spectrum of the output, thereby reducing the frequency amplitude peaks by several dB.

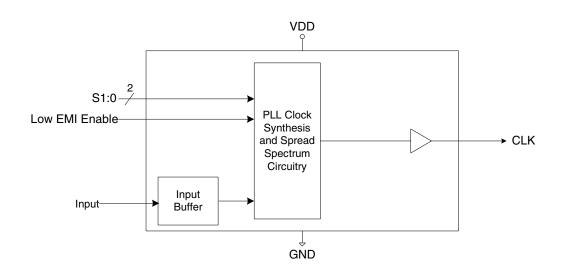
IDT offers many other clocks for computers and computer peripherals. Consult IDT when you need to remove crystals and oscillators from your board.

Features

- 8 pin SOIC package
- Pb (lead) free package
- Provides a spread spectrum output clock
- · Supports leading flat panel controllers
- Accepts a clock input, provides same frequency dithered output

MK1704A

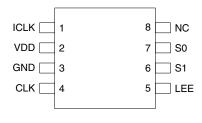
- Optimized for higher resolutions that require up to 140 MHz, as well as 40 MHz (SVGA) and 65 MHz (XVGA) clocks
- Peak reduction by 7 dB 14 dB typical on 3rd 19th odd harmonics
- Low EMI feature can be disabled
- Operating voltage of 3.3V or 5V
- Advanced, low power CMOS process
- See the MK1714-01 for a multiplier with low EMI which can operate from a crystal



Block Diagram

1

Pin Assignment



8 pin (150 mil) SOIC

Output Clock Selection Table

| S1 | S0 | | Input Nom. | | Mult. | Freq. spread vs. CLK |
|----|----|----|---------------|-----|-------|----------------------------|
| 0 | 0 | 60 | 135 | 140 | x1 | +0.5, -1.5% |
| 0 | 1 | 60 | 80 | 120 | x1 | +0.5, -1.5% |
| 1 | 0 | 30 | 40 | 60 | x1 | Down 2.5% |
| 1 | 1 | 40 | 65 | 100 | x1 | +0.5, -1.5% |

Pin Descriptions

| Pin Number | Pin Name | Pin Type | Pin Description |
|---------------|-------------|-------------|---|
| 1 | ICLK | XI | Connect to a clock input as shown in table above. |
| 2 | VDD | Power | Connect to +3.3V or +5V. |
| 3 | GND | Power | Connect to ground. |
| 4 | CLK | Output | Clock output equal to input frequency. |
| 5 | LEE | Input | Low EMI enable. Turns on the spread spectrum when high. Internal pull-up. |
| 6 | S1 | Input | Frequency select 1 input. Selects input/output clock range per table above. Internal pull-up. |
| 7 | S0 | Input | Frequency select 0 input. Selects input/output clock range per table above. Internal pull-up. |
| 8 | NC | - | No connect. Do not connect anything to this pin. |

External Components

Series Termination Resistor

Clock output traces over one inch should use series termination. To series terminate a 50Ω trace (a commonly used trace impedance), place a 33Ω resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is 20Ω

Decoupling Capacitor

A decoupling capacitor of 0.01μ F must be connected between VDD and GND on pins 2 and 3.

PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

1) The 0.01μ F decoupling capacitor should be mounted on

the component side of the board as close to the VDD pin as possible. No vias should be used between decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.

2) The external crystal should be mounted just next to the device with short traces. The X1 and X2 traces should not be routed next to each other with minimum spaces, instead they should be separated and away from other traces.

3) To minimize EMI the 33Ω series termination resistor, if needed, should be placed close to the clock output.

4) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal

layers. Other signal traces should be routed away from the MK1704A. This includes signal traces just underneath the

Powerup Considerations

To insure proper operation of the spread spectrum generation circuit, some precautions must be taken in the implementation of the MK1704A.

1) An input signal should not be applied to ICLK until VDD is stable. This requirement can easily be met by operating the MK1704A and the ICLK source from the same power supply.

2) LEE should not be enabled (taken high) until after the power supplies and input clock are stable. This requirement can be met by direct control of LEE by system logic; for

device, or on layers adjacent to the ground plane layer used by the device.

example, a "power good" signal. Another solution is to leave LEE unconnected to anything but a 0.01 μ F capacitor to ground. The pullup resistor on LEE will charge the capacitor and provide approximately a one millisecond delay until spread spectrum is enabled.

3) If the input frequency is changed during operation, disable spread spectrum until the input clock stabilizes at the new frequency. LEE should be disabled for 10 μs minimum.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the MK1704A. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

| Item | Rating |
|-------------------------------|-------------------|
| Supply Voltage, VDD | 7V |
| All Inputs and Outputs | -0.5V to VDD+0.5V |
| Ambient Operating Temperature | 0 to +70° C |
| Storage Temperature | -65 to +150° C |
| Junction Temperature | 175° C |
| Soldering Temperature | 260° C |

Recommended Operation Conditions

| Parameter | Min. | Тур. | Max. | Units |
|---|------|------|------|-------|
| Ambient Operating Temperature | 0 | | +70 | °C |
| Power Supply Voltage (measured in respect to GND) | +3.0 | | +5.5 | V |

DC Electrical Characteristics

| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|---------------------------|------------------|--------------------------|-----------|-------|-----------|-------|
| Operating Voltage | VDD | | 3.0 | | 5.5 | V |
| Supply Current | IDD | No load, 3.3V | | 10 | | mA |
| | | No load, 5V | | 15 | | mA |
| Input High Voltage | V _{IH} | Clock input | (VDD/2)+1 | VDD/2 | | V |
| Input Low Voltage | V _{IL} | Clock input | | VDD/2 | (VDD/2)-1 | V |
| Output High Voltage | V _{OH} | I _{OH} = -4 mA | VDD-0.4 | | | V |
| Output High Voltage | V _{OH} | I _{OH} = -25 mA | 2.4 | | | V |
| Output Low Voltage | V _{OL} | I _{OL} = 25 mA | | | 0.4 | V |
| Input Capacitance | C _{IN} | S0 pin | | 7 | | pF |
| Nominal Output Impedance | Z _{OUT} | | | 20 | | Ω |
| Internal Pull-up Resistor | R _{PU} | LEE pin only | | 500 | | kΩ |

Unless stated otherwise, VDD = 5V, Ambient Temperature 0 to $+70^{\circ}$ C

AC Electrical Characteristics

Unless stated otherwise, VDD = 5V, Ambient Temperature 0 to $+70^{\circ}$ C

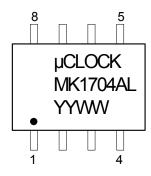
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|---|-----------------|--------------------------|------|-------|------|-------|
| Input Frequency | | S1=0, S0=0 | 60 | 135 | 140 | MHz |
| | | S1-0, S0=1 | 60 | 80 | 120 | MHz |
| | | S1=1, S0=0 | 30 | 40 | 60 | MHz |
| | | S1=1, S0=1 | 40 | 65 | 100 | MHz |
| Input Clock Duty Cycle | | Time above VDD/2 | 20 | | 80 | % |
| Output Rise Time | t _{OR} | 0.8 to 2.0V, Note 1 | | | 1.5 | ns |
| Output Fall Time | t _{OF} | 2.0 to 0.8V, Note 1 | | | 1.5 | ns |
| Output Clock Duty Cycle | | Time above 1.5V | 40 | 50 | 60 | % |
| Output Clock Frequency Variation from Mean | | | | 1-2.5 | | % |
| EMI Peak Frequency Reduction | | 3rd - 19th odd harmonics | | 10-16 | | dB |

Note 1: Measured with 15pF load

Thermal Characteristics

| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|-------------------------------------|---------------|----------------|------|------|------|-------|
| Thermal Resistance Junction to | θ_{JA} | Still air | | 150 | | ° C/W |
| Ambient | θ_{JA} | 1 m/s air flow | | 140 | | ° C/W |
| | θ_{JA} | 3 m/s air flow | | 120 | | ° C/W |
| Thermal Resistance Junction to Case | θ_{JC} | | | 40 | | ° C/W |

Marking Diagram (Pb free)



Notes:

1. YYWW is the last two digits of the year and week the part was assembled.

2. "L" denotes Pb (lead) free package

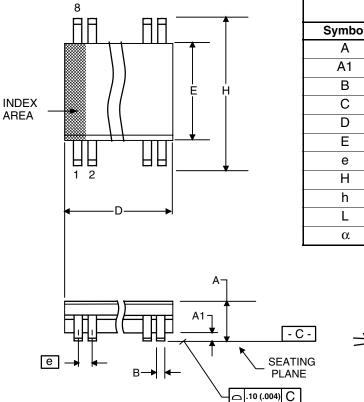
3. Bottom Markings:

= lot number

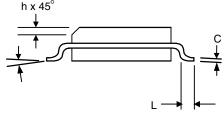
(origin) = country of origin if not USA

Package Outline and Package Dimensions (8 pin SOIC, 150 Mil. Body)

Package dimensions are kept current with JEDEC Publication No. 95



| | Millin | neters | Inc | hes | |
|--------|--------|------------|-------------|-------|--|
| Symbol | Min | Max | Min | Max | |
| A | 1.35 | 1.75 | .0532 | .0688 | |
| A1 | 0.10 | 0.25 | .0040 | .0098 | |
| В | 0.33 | 0.51 | .013 | .020 | |
| С | 0.19 | 0.25 | .0075 | .0098 | |
| D | 4.80 | 5.00 | .1890 | .1968 | |
| E | 3.80 | 4.00 | .1497 | .1574 | |
| е | 1.27 E | BASIC | 0.050 BASIC | | |
| Н | 5.80 | 6.20 | .2284 | .2440 | |
| h | 0.25 | 0.50 | .010 | .020 | |
| L | 0.40 | 1.27 | .016 | .050 | |
| α | 0° | 8 ° | 0 ° | 8° | |



Ordering Information

| Part / Order Number | Marking | Shipping Packaging | Package | Temperature |
|---------------------|------------|--------------------|------------|-------------|
| MK1704ALF | | Tubes | 8 pin SOIC | 0 to +70° C |
| MK1704ALFTR | see page 5 | Tape and Reel | 8 pin SOIC | 0 to +70° C |

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TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

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